

Ultrafast Exciton Dynamics in the Atomically Thin van der Waals Magnet CrSBr

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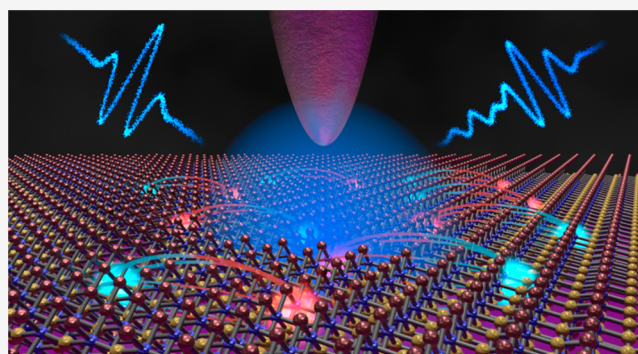
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Supporting Information

ABSTRACT: Among atomically thin semiconductors, CrSBr stands out as both its bulk and monolayer forms host tightly bound, quasi-one-dimensional excitons in a magnetic environment. Despite its pivotal importance for solid-state research, the exciton lifetime has remained unknown. While terahertz polarization probing can directly trace all excitons, independently of interband selection rules, the corresponding large far-field foci substantially exceed the lateral sample dimensions. Here, we combine terahertz polarization spectroscopy with near-field microscopy to reveal a femtosecond decay of paramagnetic excitons in a monolayer of CrSBr, which is 30 times shorter than the bulk lifetime. We unveil low-energy fingerprints of bound and unbound electron–hole pairs in bulk CrSBr and extract the nonequilibrium dielectric function of the monolayer in a model-free manner. Our results demonstrate the first direct access to the ultrafast dielectric response of quasi-one-dimensional excitons in CrSBr, potentially advancing the development of quantum devices based on ultrathin van der Waals magnets.

KEYWORDS: *atomically thin solids, van der Waals magnets, anisotropic excitons, ultrafast dynamics, femtosecond near-field microscopy, terahertz*



The advent of magnetic two-dimensional crystals hosting strongly bound excitons has initiated an unparalleled development in the realm of quantum materials.^{1–6} In these systems, magnetic order fundamentally influences excitonic properties, such as effective mass, eigenenergies, and polarization, spawning a variety of emergent quantum phenomena.^{7–10} The van der Waals layered magnet CrSBr stands out particularly for its intricate interplay between magnetic order and quasi-one-dimensional electronic and lattice structure,^{11–22} establishing CrSBr as a unique platform for fundamental research and future quantum devices. In CrSBr, electron–hole pairs form highly anisotropic excitons whose real-space wave function extends along the in-plane crystallographic *b* axis. Below its Néel temperature of $T_N = 132$ K, bulk CrSBr features in-plane ferromagnetic order among layers, which are antiferromagnetically coupled along the stacking direction, while quasi-one-dimensional excitons are strongly localized within individual layers. The breakdown of magnetic order in the paramagnetic phase, above T_N , should result in a more 2D character of excitons tunneling between adjacent layers. In the monolayer limit, the out-of-plane confinement causes the quasi-one-dimensional nature of excitons to persist even beyond room temperature.

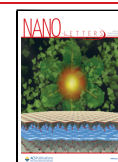
The combination of tight spatial confinement of excitons in the Cr–S chains and the separation of the van der Waals layers by the Br atoms has been reported to result in high exciton binding energies of ~ 0.7 and ~ 0.1 eV in monolayers and bulk, respectively.²² These robust excitons pave the way for applications in optoelectronics and quantum information processing at room temperature. While clear photoluminescence signatures of exciton recombination were identified at a photon energy of 1.37 eV,²² the actual size of the single-particle bandgap in CrSBr is still under debate.²³ Scanning tunneling spectroscopy (STS) measurements have estimated the bulk bandgap to amount to 1.5 ± 0.2 eV,^{7,22} whereas the bandgap of monolayer CrSBr has only been predicted by theory. To selectively prepare and study unbound electron–hole pairs above the bandgap or excitons, pump–probe

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measurements with tunable excitation wavelengths are hence desirable.

Recent studies of CrSBr have primarily focused on controlling exciton-coupled magnons at radio frequencies using magnetic fields and cavity photons.^{9–11} Meanwhile, the ultrafast dynamics of nonequilibrium electron–hole pairs has remained unexplored, to the best of our knowledge. Particularly, the potential impact of short-lived magnetic fluctuations, so-called paramagnons,^{24,25} on exciton dynamics has not been considered yet. Terahertz (THz) time-domain spectroscopy²⁶ provides a unique tool to trace the ultrafast dielectric response of photoexcited electron–hole pairs. However, as the micron-scale lateral dimensions of typical exfoliated CrSBr monolayers are much smaller than the diffraction limit of THz pulses, subwavelength spatial resolution is a prerequisite for conclusive studies.

Here, we employ ultrafast polarization nanoscopy,^{27,28} a technique based on time-resolved near-field microscopy^{29–33} at THz frequencies,^{34–37} to explore the dynamics of electron–hole pairs in paramagnetic CrSBr. Following optical excitation by tunable femtosecond laser pulses, THz probe fields directly trace the dynamics of continuum states and excitons regardless of interband selection rules. Our nanoscopic subcycle approach allows us to resolve the femtosecond decay and the dielectric response of unbound electron–hole pairs and quasi-one-dimensional excitons in bulk and atomically thin CrSBr, for the first time. Furthermore, we observe ultrafast relaxation of excitons in bulk CrSBr in which scattering with paramagnons could occur.

Figure 1a shows an optical micrograph of a typical CrSBr sample exfoliated on a SiO₂ layer (thickness, 285 nm) fabricated on a p⁺⁺-doped silicon substrate. The depicted area contains both bulk (yellow/blue) and monolayer (ML, faint blue) flakes, which, owing to the structural anisotropy of CrSBr, extend along the crystallographic *a* axis. The micrometer-sized lateral dimensions of the monolayers are much smaller than the diffraction limit of THz pulses. To overcome this mismatch, we couple phase-locked THz waveforms (blue) to the apex of a metallic tip of an atomic force microscope (Figure 1b and section 1 in the Supporting Information). The confined evanescent near field interacts with the sample in a nanoscopic area on the order of the tip's radius of curvature. Therefore, the nanoscale dielectric response of the sample is imprinted in the scattered THz electric field, which we retrieve by electro-optic sampling (EOS) and demodulation of the signal at the oscillation frequency of the tip.

Moreover, the sample can be photoexcited with ultrashort optical pulses (pulse duration <100 fs) from a noncollinear optical parametric amplifier, allowing us to tune the pump photon energy, $h\nu_p$, between 1.30 and 2.41 eV (section 2 in the Supporting Information). This enables us to selectively inject electron–hole pairs in excitonic or continuum states (Figure 1c, left). The THz electric near field features components along the highly polarizable *b*-axis (blue arrow),²⁷ inducing each electron–hole pair to carry a dipole moment, p , which is proportional to the polarizability, α . By analyzing the pump-induced change in the scattered THz field, ΔE , we can discriminate between highly polarizable unbound electron–hole pairs and excitons, whose polarizability is reduced by Coulomb binding (Figure 1c, right). Importantly, owing to the small pump spot size ($\sim 5 \mu\text{m}$), signal contributions from regions far away from the tip are excluded from ΔE . Figure 1d displays the electro-optically detected steady-state near-field

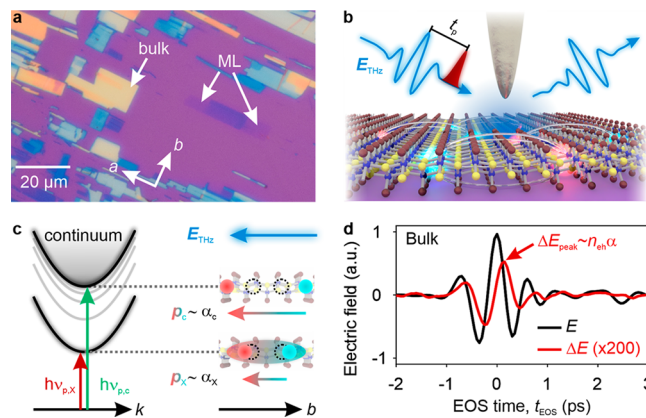


Figure 1. Probing ultrafast electron–hole pair dynamics in bulk and monolayer CrSBr by THz polarization nanoscopy. (a) Optical micrograph of a typical CrSBr sample including bulk (yellow, blue) and monolayer (ML, faint blue) flakes. The crystallographic *a*- and *b*-axes are indicated. (b) Schematic of the THz near-field spectroscopy technique. Optical pump pulses (red) tunable in photon energy generate electron–hole pairs in CrSBr. After a variable delay time, t_p , a phase-locked THz probe transient, E_{THz} (blue, left), is coupled into the evanescent near field of a metallic tip. By phase-resolved detection of the scattered THz waveform (blue, right) information about the nanoscale dielectric function of the sample is obtained. (c) Polarization nanoscopy. Tunable pump pulses excite either excitons (red, $h\nu_{p,x}$) or continuum states (green, $h\nu_{p,c}$). The THz electric field (blue arrow) polarizes the electron–hole pairs with polarizability α_x and α_c , respectively. (d) Electro-optically detected steady-state scattered THz waveform, E (black line), and pump-induced change, ΔE (red line), of a bulk CrSBr flake at a pump delay, $t_p = 0.5$ ps, as a function of the EOS time, t_{EOS} .

response of a CrSBr bulk flake, E (black curve), together with a typical pump-induced change (red curve), recorded at a pump delay time $t_p = 0.5$ ps after photoexcitation with $h\nu_p = 1.39$ eV. ΔE roughly traces E with a phase shift of about $\pi/3$. The spectra of E and ΔE will be discussed later in the text.

To gain first insights into the lifetime of electron–hole pairs in bulk and monolayer CrSBr, we record the maximum pump-induced change of the scattered THz transient, which is proportional to the density, n_{eh} , and polarizability, α , of photoexcited electron–hole pairs, $\Delta E_{\text{peak}} \propto n_{\text{eh}}\alpha$, as a function of t_p . We set the pump polarization along the *b*-axis because the corresponding optical interband transitions are dipole-allowed in this direction, while they are forbidden along the *a*-axis.¹⁴ Figure 2a shows the pump–probe dynamics of the THz near-field response (electro-optic delay time, $t_{\text{EOS}} = 0.15$ ps) in bulk CrSBr (thickness, 400 nm) for a pump fluence $\Phi_p = 5 \text{ mJ cm}^{-2}$ and photon energies $1.30 \text{ eV} \leq h\nu_p \leq 1.81 \text{ eV}$, spanning both the 1s exciton resonance at 1.37 eV and the reported bandgap of 1.5 ± 0.2 eV. To gauge the contribution per electron–hole pair, we divide ΔE_{peak} by the respective electron–hole pair density, n_{eh} , weighted with the finite probing depth of the THz near field (section 3 in the Supporting Information). Irrespective of $h\nu_p$, the pump-induced signal grows abruptly upon photoexcitation, reaches its maximum at $t_p = 0.5$ ps, and subsequently decays with biexponential behavior.

While we observe a slow decay time ($1/e$), $\tau_{\text{slow}} = 15 \pm 3$ ps common to all data sets, the fast initial decay strongly depends on $h\nu_p$. For $h\nu_p = 1.39, 1.46,$ and 1.65 eV, we extract an initial decay time, $\tau_{\text{fast}} = 1.6 \pm 0.3$ ps. However, at $h\nu_p = 1.81$ eV, this decay takes place faster within $\tau_{\text{fast}} = 1.0 \pm 0.1$ ps. Moreover, the amplitude of ΔE_{peak} is significantly higher (gray area) than

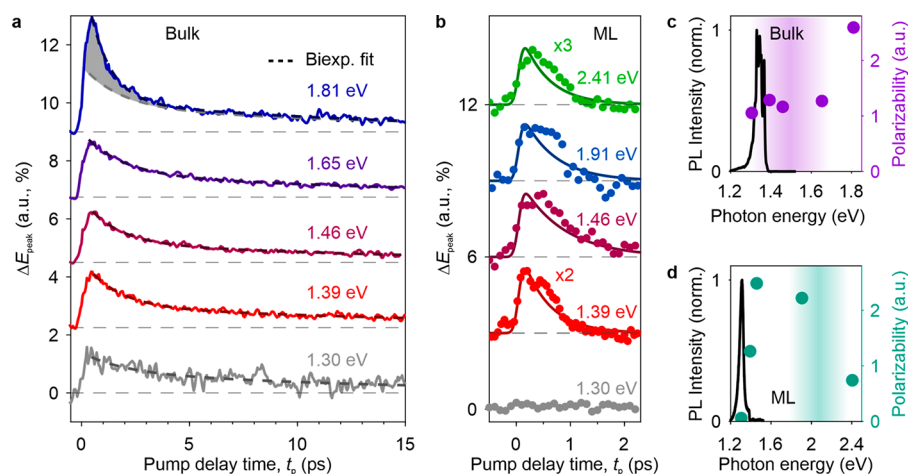


Figure 2. Femtosecond electron–hole pair dynamics in bulk and monolayer CrSBr. (a) Maximal pump-induced change of the near-field response at $t_{\text{EOS}} = 0.15$ ps, ΔE_{peak} of bulk CrSBr as a function of pump delay time, t_p , for various excitation photon energies (solid lines). The decay of ΔE_{peak} is fitted with a biexponential function (dashed lines). The gray shaded region in the top panel shows the excess of the pump-induced signal at early delays with respect to lower excitation photon energies. The data are offset for clarity. (b) Analogous to (a) for the monolayer (ML) limit. Solid lines are calculated with a rate equation model. (c, d) Polarizability of the photoexcited electron–hole pairs as a function of the pump photon energy for bulk (purple circles) and monolayer (teal circles). For context, the low-temperature photoluminescence spectra (PL, solid lines) as well as bandgaps measured with STS (bulk, purple ribbon)⁷ and predicted by GW calculations (ML, teal ribbon)²² are shown.

that for lower $h\nu_p$, suggesting that different species of electron–hole pairs are involved throughout the decay. For excitation below the bandgap, we expect to initially prepare hot excitons, which relax into the 1s ground state within about 1.6 ps. The thermalization may result from scattering with phonons or short-range spin correlations, that is, paramagnons.^{24,25} We attribute the slow decay common to all photon energies to the recombination of 1s excitons with lifetimes of ~ 15 ps. In contrast, the fast decay of the polarization signal at $h\nu_p = 1.81$ eV is indicative of the formation of 1s excitons; when excitons from energetically more distant bands or unbound electron–hole pairs bind into 1s states, their polarizability is quenched by Coulomb attraction. We will investigate the different excitation scenarios in more detail with complementary measurements presented further below.

Proceeding from bulk to monolayer CrSBr, we estimate that depending on the excitation energy only a few tens to hundreds of electron–hole pairs are probed in the near-field volume of the tip. The excellent sensitivity of our setup enables us to still detect their femtosecond dynamics. We trace ΔE_{peak} as a function of t_p for $h\nu_p = 1.30$ eV (below the 1s state), 1.39, 1.46, 1.91 eV (above the 1s state), and 2.41 eV (above the calculated bandgap), as shown in Figure 2b. The applied pump fluences were restricted to $\Phi_p \leq 2.5$ mJ cm⁻², which is safely below the damage threshold of the monolayer. At $h\nu_p = 1.30$ eV, below the exciton resonance, no pump-induced change in the THz signal is detectable. In contrast, when the pump photon energy is sufficient to excite excitons, we see an abrupt increase of ΔE_{peak} followed by an ultrafast, subpicosecond decay. The observed dynamics can thus be assigned to the excitation and decay of excitons in monolayer CrSBr.

As ΔE_{peak} changes on time scales comparable to the duration of our pump and gate pulses (~ 100 fs), for a quantitative investigation, we simulate the time evolution of ΔE_{peak} with a rate equation model comprising a source term given by the pump pulse and a subsequent exponential decay (section 4 in the Supporting Information). The model accurately reproduces the observed onset and decay (solid lines) and thus allows us

to directly gauge the exciton lifetime in monolayer CrSBr, for the first time. The best agreement with the experimental data is achieved with an exciton lifetime of 0.5 ps, which is 30 times faster than the decay observed in the bulk. Due to the large oscillator strength of quasi-one-dimensional excitons, we expect an ultrashort radiative lifetime in the monolayer, which we estimate to be of the order of 1 ps (section 5 in the Supporting Information). Yet the decay is unaffected by the pump photon energy, suggesting an important contribution also from nonradiative recombination. As the dynamics are independent of the pump fluence, we can rule out Auger processes, leaving radiative recombination and recombination at defects and surface impurities as the most important decay channels.

Polarization excitation spectroscopy can reveal how the polarizability of the initially photoexcited electron–hole pairs depends on their binding state. To this end, the maximum of ΔE_{peak} at $t_p = 0.5$ ps (bulk) and $t_p = 0.4$ ps (monolayer), respectively, is traced as a function of $h\nu_p$ (Figure 2c,d). For comparison, the data are overlaid with the measured low-temperature photoluminescence spectrum of bulk and monolayer CrSBr as well as the bandgaps obtained from STS (bulk) and calculations (monolayer), respectively. The polarizability of the photoexcited bulk sample (Figure 2c, purple circles) is constant for 1.30 eV $\leq h\nu_p \leq 1.65$ eV, whereas the polarizability dramatically increases for $h\nu_p = 1.81$ eV, indicating a dominant contribution of electron–hole pairs exhibiting weak or no Coulomb binding. In the monolayer, the polarizability increases upon photoexcitation above the 1s ground state at a photon energy of 1.37 eV. After a plateau at $h\nu_p = 1.46$ and 1.91 eV, the polarizability decreases by a factor of 3, when $h\nu_p$ is tuned to 2.41 eV. This reduction contrasts with the bulk polarizability spectrum and suggests the observation of a less polarizable, more strongly bound exciton originating from a lower valence band with higher effective masses, which has been theoretically predicted.²⁷

While recording ΔE_{peak} provides helpful insights into the polarizability and the decay dynamics of photoexcited electron–hole pairs, a quantitative analysis of the binding

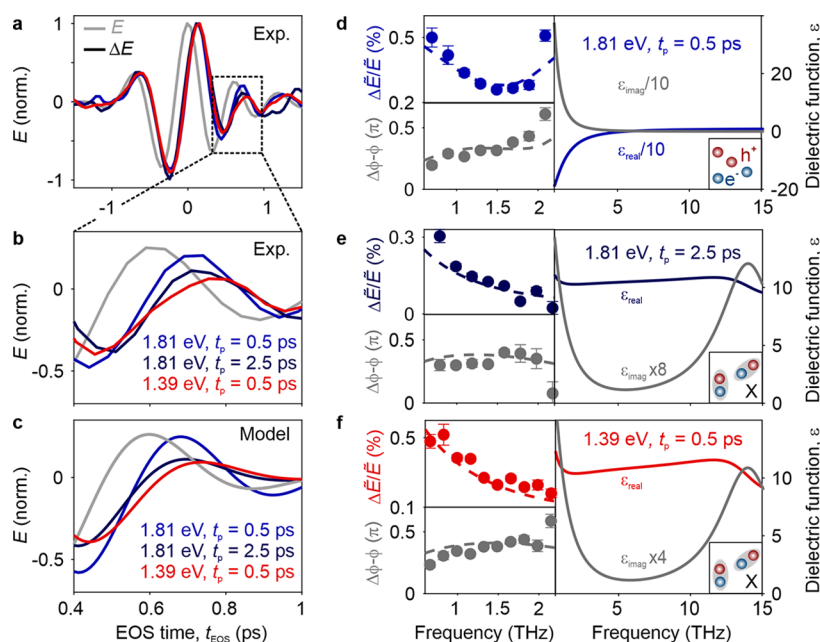


Figure 3. Identifying species of photoexcited electron–hole pairs in bulk CrSbBr by THz near-field spectroscopy. (a) Experimental pump-induced changes of the scattered THz waveform, ΔE , on bulk CrSbBr as a function of the EOS time, t_{EOS} , for different pump photon energies and pump delay times, t_p . The steady-state near-field response is shown in gray. (b) Zoom-in to the EOS time window between 0.4 and 1 ps. (c) Time-domain near-field responses modeled with the finite-dipole model. (d–f) Relative spectral amplitude, $\Delta\tilde{E}/\tilde{E}$ (top left panels), and phase, $\Delta\phi - \phi$ (bottom left panels), of the near-field response. The modeled data (dashed lines) calculated with the dielectric functions either comprising a Drude term (d) or two Lorentzians (e, f), shown in the right panels, excellently reproduce the measurements (circles).

states of the photoexcited electron–hole pairs calls for complete THz near-field spectroscopy. To this end, the scattered THz waveform is electro-optically sampled for various $h\nu_p$ and t_p . We focus on excitation close to the 1s exciton resonance ($h\nu_p = 1.39$ eV) and above the bandgap (1.81 eV). Based on the dynamics shown in Figure 2a, the observed ultrafast initial decay of ΔE_{peak} for $h\nu_p = 1.81$ eV has been associated with the dynamics of electron–hole pairs binding into 1s excitons. To test this hypothesis, we compare the pump-induced near-field responses at $t_p = 0.5$ and 2.5 ps, which would originate from unbound electron–hole pairs or excitons from energetically lower valence bands and 1s excitons, respectively. Figure 3a depicts the steady-state scattered near-field waveform, E (gray), and the pump-induced change, ΔE ($\Phi_p = 4$ mJ cm $^{-2}$), for $h\nu_p = 1.81$ eV at $t_p = 0.5$ ps (blue) and $h\nu_p = 1.39$ eV at $t_p = 0.5$ ps (red) as well as $h\nu_p = 1.81$ eV at $t_p = 2.5$ ps (dark blue). The first minimum and second maximum of all ΔE waveforms are located at zero crossings of the steady-state response. However, the transients clearly differ at positive t_{EOS} , as highlighted in Figure 3b: both the minimum at $t_{\text{EOS}} = 0.45$ ps and the maximum at $t_{\text{EOS}} = 0.70$ ps are more strongly pronounced for $h\nu_p = 1.81$ eV and $t_p = 0.5$ ps compared to the other two waveforms, which share similar amplitudes.

This difference is characteristic of distinct changes in the dielectric function. To quantitatively connect the microscopic spectral response with the time-domain signatures observed in Figure 3a, we Fourier transform the waveforms ΔE and E and consider the corresponding relative spectral amplitude, $\Delta\tilde{E}/\tilde{E}$ (Figure 3d–f, top left panels), and phase, $\Delta\phi - \phi$ (Figure 3d–f, bottom left panels), in the spectral range of our THz probe pulse. The relative spectral amplitude for $h\nu_p = 1.81$ eV and $t_p = 0.5$ ps features a minimum around 1.6 THz and increases toward the spectral edges, while $\Delta\phi - \phi$ (Figure 3d, bottom

left) monotonically increases with frequency. This response is markedly different from the two other cases (Figure 3e,f), where $\Delta\tilde{E}/\tilde{E}$ decreases monotonically with frequency, while $\Delta\phi - \phi$ shows no observable feature and stays around 0.3π .

We analyze how the dielectric response of the sample relates to the observed spectral characteristics by modeling near-field scattering off the photoexcited bulk CrSbBr sample with the finite-dipole model (section 6 in the Supporting Information). The terahertz response for $h\nu_p = 1.81$ eV and $t_p = 0.5$ ps can be reproduced best (Figure 3d, dashed line) by a Drude dielectric function shown in Figure 3d (right panel). The modeled spectrum agrees well with the experimental data, indicating the dominant contribution of unbound electron–hole pairs after photoexcitation. In contrast, the Drude response fails to explain the pump-induced change for $h\nu_p = 1.81$ eV at $t_p = 2.5$ ps and $h\nu_p = 1.39$ eV at $t_p = 0.5$ ps (Figure 3e,f, left panels). Therefore, we model the corresponding dielectric function with two Lorentzians, where one oscillator represents the strong, off-resonantly probed 1s–2p transition expected at ~ 14 THz. The second, low-energy resonator at 1 THz covers all intraexcitonic transitions from states with large principal quantum numbers (see Figure 3e,f, right panel). The pump-induced response yields excellent agreement with the experiment (Figure 3e,f, left panels). Moreover, in the modeled time-domain data (Figure 3c), the contrast between the Drude and the excitonic near-field response is evident and matches the relative amplitudes of the peaks around $t_{\text{EOS}} = 0.45$ and 0.70 ps seen in the experiment (Figure 3b).

In the monolayer sample, effects of finite probing depths and interlayer tunneling are negligible, allowing us to reliably extract the complex nonequilibrium dielectric function in a model-free manner. We record E and ΔE on a monolayer flake at $t_p = 0.4$ ps after resonant excitation of the exciton ground state ($h\nu_p = 1.39$ eV) with a fluence $\Phi_p = 1.6$ mJ cm $^{-2}$ (Figure

4a). The pump-induced change ΔE is significantly delayed with respect to E . While the first minimum of ΔE is enhanced,

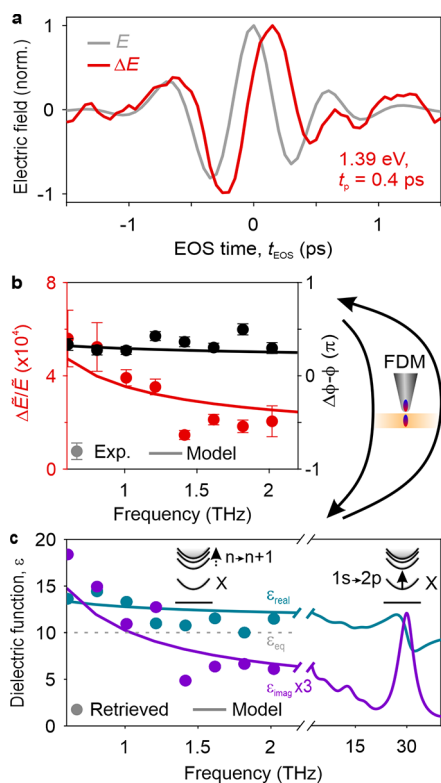


Figure 4. Extracting the complex-valued dielectric function of a photoexcited CrSBr monolayer. (a) Experimental pump-induced change of the scattered THz waveform, ΔE (red), for a pump photon energy of 1.39 eV at $t_p = 0.4$ ps. The steady-state near-field response, E , is shown in gray. (b) Relative spectral amplitude, $\Delta E/E$ (red circles), and phase, $\Delta\phi - \phi$ (black circles), of the near-field response. (c) Dielectric function obtained for an anisotropic Rytova–Keldysh confinement potential (solid lines) used to calculate the near-field response shown in (b) (solid lines). By numerically inverting the finite-dipole model, we retrieve the complex dielectric function, ϵ , of the photoexcited monolayer (circles). The assumed equilibrium dielectric function, $\epsilon_{eq} = 10$, is shown as a gray dashed line.

the second minimum is suppressed. The relative spectral amplitude (Figure 4b, red circles) decreases monotonically, while $\Delta\phi - \phi$ (black circles) is mostly flat around 0.3π . From the spectral response of the photoexcited monolayer, we can directly retrieve its complex dielectric function, ϵ , for the first time, by inverting the finite-dipole model (section 6 in the Supporting Information). The only required assumption is the steady-state dielectric function, ϵ_{eq} , which we found to be constant within our probe spectrum (section 7 in the Supporting Information). For $\epsilon_{eq} = 10$,³⁸ we obtain the nonequilibrium dielectric function depicted in Figure 4c. For frequencies below 1.2 THz, the real part of ϵ , ϵ_{real} (teal circles), is increased by $\sim 30\%$ compared to the steady state (gray dashed line). Above 1.2 THz, ϵ_{real} is only slightly larger than ϵ_{eq} . The imaginary part, ϵ_{imag} (purple circles), considerably decreases toward higher frequencies.

The increase of ϵ_{real} and ϵ_{imag} toward smaller frequencies is reminiscent of a Lorentz oscillator near the low-frequency edge of our probe spectrum, which indicates transitions between highly excited excitons. To corroborate this hypothesis, we model the dielectric function of the nonequilibrium system by

calculating the excitonic eigenstates and transition energies for a Rytova–Keldysh potential, considering the anisotropy of the effective mass (section 8 in the Supporting Information). Figure 4c depicts the real (teal line) and imaginary (purple line) parts of the modeled dielectric function. The $1s-2p$ transition manifests as a peak in ϵ_{imag} around 27 THz, while the transitions between the more narrowly spaced, higher-energy excitonic states are imprinted in the dielectric function as a steep increase of both ϵ_{real} and ϵ_{imag} for decreasing frequency, reliably capturing the shape of the retrieved dielectric function. Lastly, calculating the spectral near-field response of the photoexcited monolayer using the modeled dielectric function (Figure 4b, solid lines) yields excellent agreement with the experimental spectra. These findings provide strong evidence that, at room temperature, the terahertz dielectric response of monolayer CrSBr is dominated by transitions between highly excited, quasi-one-dimensional exciton states.

In conclusion, we explored the ultrafast dynamics of tightly bound electron–hole pairs in the van der Waals magnet CrSBr. In the bulk, we observe an ultrafast relaxation of hot excitons, which may be related to scattering with phonons, defects, or paramagnons and an exciton lifetime of 15 ps. An ultrashort recombination on the time scale of 0.5 ps is revealed in the monolayer, representing the first direct access to the femtosecond dynamics of quasi-one-dimensional excitons in an atomically thin van der Waals magnet. Analyzing the near-field response of bulk CrSBr, we can distinguish the signatures of Coulomb-bound and unbound electron–hole pairs. Furthermore, the nonequilibrium dielectric response of a photoexcited monolayer features the spectral fingerprint of internal transitions between exciton states with high principal quantum numbers. In the future, our near-field spectroscopy approach may be harnessed to investigate the temporal and spectral signatures of coupling of excitons to the various magnetic phases of CrSBr, ultimately even allowing one to image magnetic domains and observe magnetic phase transitions on the nanoscale. Moreover, polarization nanoscopy poses an ideal probe for strain-induced modulations of electronic and magnetic order^{39,40} as well as moiré-twisted van der Waals magnets,⁴¹ which are promising candidates for next-generation spintronic devices.

■ ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.nanolett.3c05010>.

Ultrafast THz near-field spectroscopy setup, tunable optical pump pulses from a noncollinear optical parametric amplifier (NOPA), estimation of the electron–hole pair density, rate-equation model for the ultrafast dynamics of electron–hole pairs, estimating the radiative exciton lifetime in monolayer CrSBr, modeling the spectral near-field response, steady-state nanospectroscopy of monolayer CrSBr, modeling the nonequilibrium dielectric function of monolayer CrSBr, and dependence of the pump–probe dynamics on the pump polarization (PDF)

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Author Contributions

C.M., F.D., and R.H. conceived the study. C.M., J.S., M.Z., and M.A.H. performed the ultrafast near-field experiments, analyzed the data, and calculated the finite-dipole scattering model. C.M., J.S., M.L., and N.N. calculated the exciton wave functions. S.T., A.C., and F.D. performed the low-temperature photoluminescence measurements. K.M. and Z.S. synthesized high-quality CrSBr crystals. All authors contributed to the discussions of the results. C.M., J.S., N.N., F.D., and R.H. wrote the manuscript with input from all authors.

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Notes

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REFERENCES

- (1) Huang, B.; et al. Layer-dependent ferromagnetism in a van der Waals crystal down to the monolayer limit. *Nature* **2017**, *546*, 270–273.
- (2) Seyler, K. L.; et al. Ligand-field helical luminescence in a 2D ferromagnetic insulator. *Nat. Phys.* **2018**, *14*, 277–281.
- (3) Burch, K. S.; Mandrus, D.; Park, J. G. Magnetism in two-dimensional van der Waals materials. *Nature* **2018**, *563*, 47–52.
- (4) Kang, S.; et al. Coherent many-body exciton in van der Waals antiferromagnet NiPS₃. *Nature* **2020**, *583*, 785–789.
- (5) Hwangbo, K.; et al. Highly anisotropic excitons and multiple phonon bound states in a van der Waals antiferromagnetic insulator. *Nat. Nanotechnol.* **2021**, *16*, 655–660.
- (6) Wang, Q. H.; et al. The Magnetic Genome of Two-Dimensional van der Waals Materials. *ACS Nano* **2022**, *16*, 6960–7079.
- (7) Telford, E. J.; et al. Layered Antiferromagnetism Induces Large Negative Magnetoresistance in the van der Waals Semiconductor CrSBr. *Adv. Mater.* **2020**, *32*, No. 2003240.
- (8) Dirnberger, F.; et al. Spin-correlated exciton–polaritons in a van der Waals magnet. *Nat. Nanotechnol.* **2022**, *17*, 1060–1064.
- (9) Bae, Y. J.; et al. Exciton-coupled coherent magnons in a 2D semiconductor. *Nature* **2022**, *609*, 282–286.
- (10) Diederich, G. M.; et al. Tunable interaction between excitons and hybridized magnons in a layered semiconductor. *Nat. Nanotechnol.* **2023**, *18*, 23–28.
- (11) Dirnberger, F.; et al. Magneto-optics in a van der Waals magnet tuned by self-hybridized polaritons. *Nature* **2023**, *620*, 533–538.
- (12) Lee, K.; et al. Magnetic Order and Symmetry in the 2D Semiconductor CrSBr. *Nano Lett.* **2021**, *21*, 3511–3517.
- (13) Rizzo, D. J.; et al. Visualizing Atomically Layered Magnetism in CrSBr. *Adv. Mater.* **2022**, *34*, No. 2201000.
- (14) Wilson, N. P.; et al. Interlayer electronic coupling on demand in a 2D magnetic semiconductor. *Nat. Mater.* **2021**, *20*, 1657–1662.
- (15) Klein, J.; et al. Control of structure and spin texture in the van der Waals layered magnet CrSBr. *Nat. Commun.* **2022**, *13*, 5420.
- (16) Liu, W.; et al. A Three-Stage Magnetic Phase Transition Revealed in Ultrahigh-Quality van der Waals Bulk Magnet CrSBr. *ACS Nano* **2022**, *16*, 15917–15926.
- (17) Xu, X.; et al. Strong Spin-Phonon Coupling in Two-Dimensional Magnetic Semiconductor CrSBr. *J. Phys. Chem. C* **2022**, *126*, 10574–10583.
- (18) Wu, F.; et al. Quasi-1D Electronic Transport in a 2D Magnetic Semiconductor. *Adv. Mater.* **2022**, *34*, No. 2109759.
- (19) Klein, J.; et al. Sensing the Local Magnetic Environment through Optically Active Defects in a Layered Magnetic Semiconductor. *ACS Nano* **2023**, *17*, 288–299.

- (20) Torres, K.; et al. Probing Defects and Spin-Phonon Coupling in CrSBr via Resonant Raman Scattering. *Adv. Funct. Mater.* **2023**, *33*, No. 2211366.
- (21) Pawbake, A.; et al. Raman scattering signatures of strong spin-phonon coupling in the bulk magnetic van der Waals material CrSBr. *Phys. Rev. B* **2023**, *107*, No. 075421.
- (22) Klein, J.; et al. The Bulk van der Waals Layered Magnet CrSBr is a Quasi-1D Material. *ACS Nano* **2023**, *17*, 5316–5328.
- (23) Bianchi, M.; et al. Paramagnetic Electronic Structure of CrSBr: Comparison between Ab Initio GW Theory and Angle-Resolved Photoemission Spectroscopy. *Phys. Rev. B* **2023**, *107*, No. 235107.
- (24) Zheng, Y.; et al. Paramagnon drag in high thermoelectric figure of merit Li-doped MnTe. *Sci. Adv.* **2019**, *5*, No. eaat9461.
- (25) Wang, L.; et al. Paramagnons and high-temperature superconductivity in a model family of cuprates. *Nat. Commun.* **2022**, *13*, 3163.
- (26) Leitenstorfer, A.; et al. The 2023 terahertz science and technology roadmap. *J. Phys. D: Appl. Phys.* **2023**, *56*, No. 223001.
- (27) Plankl, M.; et al. Subcycle contact-free nanoscopy of ultrafast interlayer transport in atomically thin heterostructures. *Nat. Photonics* **2021**, *15*, 594–600.
- (28) Siday, T.; et al. Ultrafast Nanoscopy of High-Density Exciton Phases in WSe₂. *Nano Lett.* **2022**, *22*, 2561–2568.
- (29) Eisele, M.; et al. Ultrafast multi-terahertz nano-spectroscopy with sub-cycle temporal resolution. *Nat. Photonics* **2014**, *8*, 841–845.
- (30) Wagner, M.; et al. Ultrafast and Nanoscale Plasmonic Phenomena in Exfoliated Graphene Revealed by Infrared Pump-Probe Nanoscopy. *Nano Lett.* **2014**, *14*, 894–900.
- (31) Ni, G. X.; et al. Ultrafast optical switching of infrared plasmon polaritons in high-mobility graphene. *Nat. Photonics* **2016**, *10*, 244–247.
- (32) Huber, M. A.; et al. Femtosecond photo-switching of interface polaritons in black phosphorus heterostructures. *Nat. Nanotechnol.* **2017**, *12*, 207–211.
- (33) Sternbach, A. J.; et al. Programmable hyperbolic polaritons in van der Waals semiconductors. *Science* **2021**, *371*, 617–620.
- (34) Kim, R. H. J.; et al. Terahertz Nanoimaging of Perovskite Solar Cell Materials. *ACS Photonics* **2022**, *9*, 3550–3556.
- (35) Klarskov, P.; et al. Nanoscale Laser Terahertz Emission Microscopy. *ACS Photonics* **2017**, *4*, 2676–2680.
- (36) Zhang, J.; et al. Terahertz Nanoimaging of Graphene. *ACS Photonics* **2018**, *5*, 2645–2651.
- (37) Pizzuto, A.; et al. Nonlocal Time-Resolved Terahertz Spectroscopy in the Near Field. *ACS Photonics* **2021**, *8*, 2904–2911.
- (38) Wang, T.; et al. Magnetically-dressed CrSBr exciton-polaritons in ultrastrong coupling regime. *Nat. Commun.* **2023**, *14*, 5966.
- (39) Esteras, D. L.; et al. Straintronics in the 2D van der Waals Ferromagnet CrSBr from First-Principles. *Nano Lett.* **2022**, *22*, 8771–8778.
- (40) Cenker, J.; et al. Reversible strain-induced magnetic phase transition in a van der Waals magnet. *Nat. Nanotechnol.* **2022**, *17*, 256–261.
- (41) Boix-Constant, C.; et al. Multistep magnetization switching in orthogonally twisted ferromagnetic monolayers. *Nat. Mater.* **2024**, *23*, 212–218.